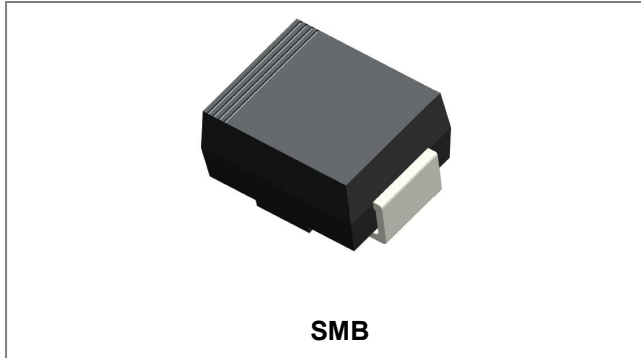




# THE DATASHEET OF SK26



## SK22 THRU SK210 SCHOTTKY RECTIFIER



### Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Circuit Diagram



### Mechanical Data

- Case: Low Profile Molded plastic
- Terminals: Plated leads solderable per MIL-STD-750, Method 2026 guaranteed
- Polarity: Color band or cathode Notch
- Mounting Position: Any
- Weight: 0.09grams(approx)

### Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Characteristic	Symbol	SK22	SK23	SK24	SK25	SK26	SK28	SK29	SK210	Units
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	20	30	40	50	60	80	90	100	V
Working Peak Reverse Voltage	V <sub>RWM</sub>									
DC Blocking Voltage	V <sub>R</sub>									
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	64	71	V
Average Rectified Output Current @T <sub>L</sub> = 105°C	I <sub>O</sub>	2.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	50								A
Forward Voltage @ I <sub>O</sub> = 2.0 A	V <sub>F</sub>	0.55		0.70		0.85				V
Peak Reverse Current @T <sub>A</sub> = 25°C	I <sub>RM</sub>	0.5								mA
At Rated DC Blocking Voltage @T <sub>A</sub> = 100°C		20								
Typical Thermal Resistance Junction to Ambient (Note 1)	R <sub>θJA</sub>	75								K/W
Operating Temperature Range	T <sub>J</sub>	-65 to +125								°C
Storage Temperature Range	T <sub>STG</sub>	-65 to +150								°C

Note: 1. mounted on P.C. Board with 8.0mm<sup>2</sup> copper pad areas.

- China - Germany - Korea - Singapore - United States •
- <http://www.smc-diodes.com> - [sales@smc-diodes.com](mailto:sales@smc-diodes.com) •

**Ratings and Characteristics Curves**

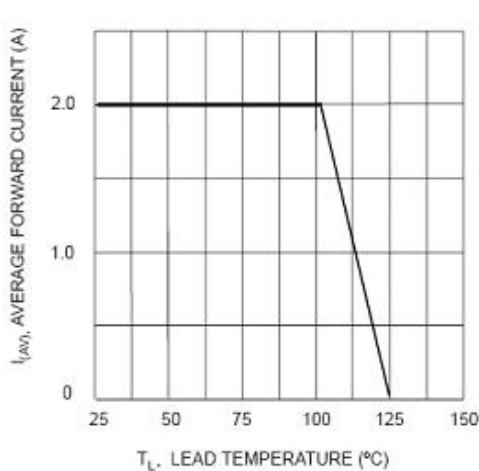


Fig. 1 Forward Current Derating Curve

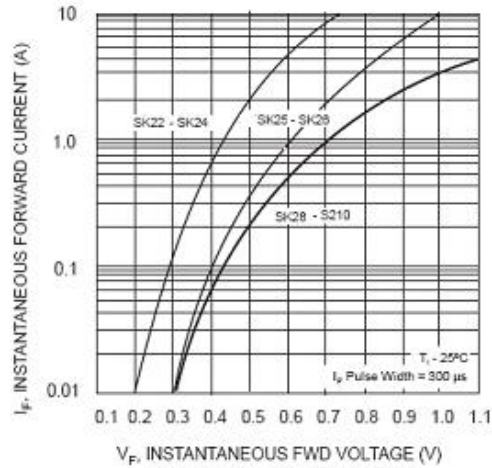


Fig. 2 Typ. Forward Characteristics

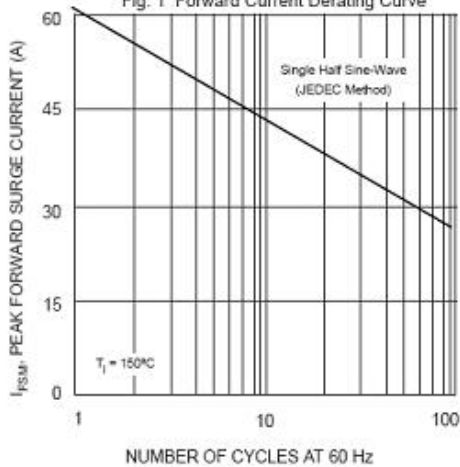


Fig. 3 Max Non-Repetitive Peak Fwd Surge Current

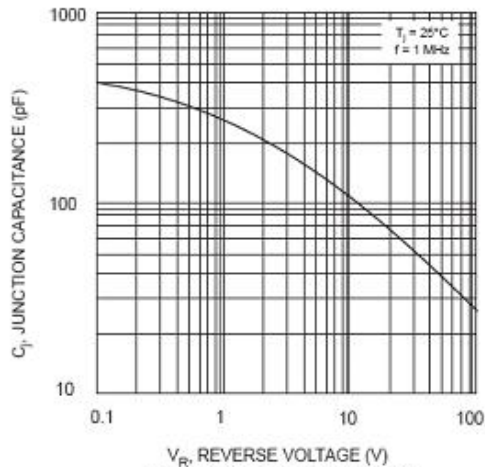


Fig. 4 Typical Junction Capacitance

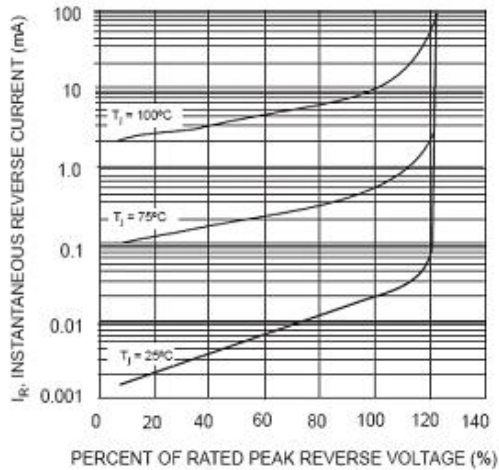
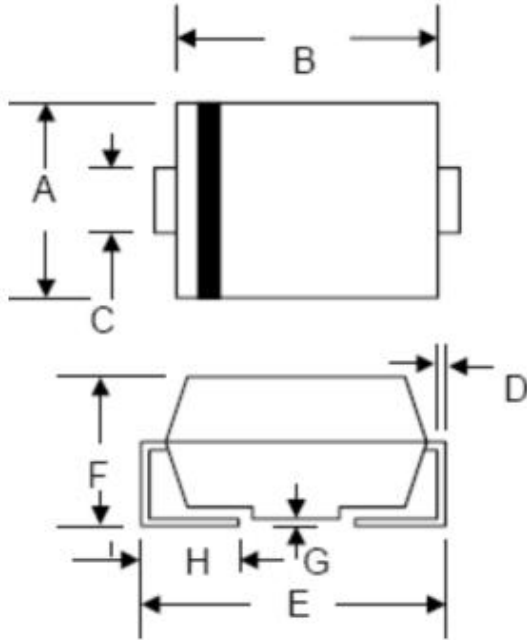


Fig. 5 Typical Reverse Characteristics

**Mechanical Dimensions SMB**



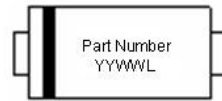
SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	3.30	3.94	0.130	0.155
B	4.06	4.70	0.160	0.185
C	1.80	2.20	0.071	0.087
D	0.152	0.305	0.006	0.012
E	4.80	5.59	0.189	0.220
F	2.10	2.60	0.083	0.102
G	0.051	0.203	0.002	0.008
H	0.76	1.52	0.030	0.060

**Ordering Information**

Device	Package	Shipping
SK22 THRU SK210	SMB (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

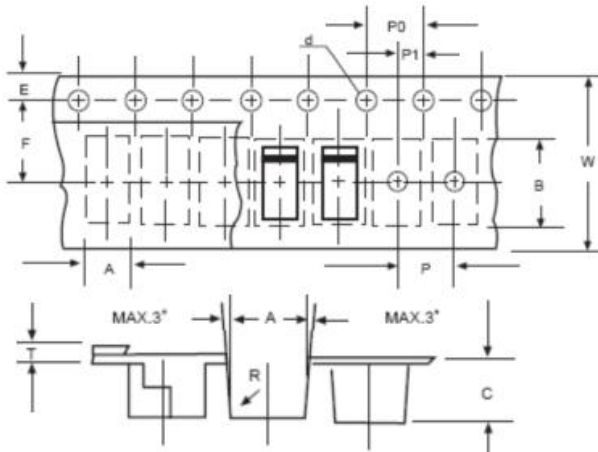
**Marking Diagram**



Where XXXXX is YYWWL

First row: Part Number (SK22, SK23, SK24, SK25, SK26, SK28, SK29, SK210)  
Second row: YYWWL  
YY is the manufacture year,  
WW is the manufacture week code,  
L is the wafer's Lot Number

**Carrier Tape Specification SMB**



SYMBOL	Millimeters	
	Min.	Max.
A	2.97	3.17
B	5.70	5.90
C	2.32	2.52
d	1.40	1.60
E	1.40	1.60
F	5.60	5.70
P	3.90	4.10
P0	3.90	4.10
P1	1.90	2.10
T	0.25	0.35
W	11.80	12.20

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